

Photocouplers Infrared LED & Photo IC

TLX9310

1. Applications

- · Automotive
- · Battery Management System (BMS)

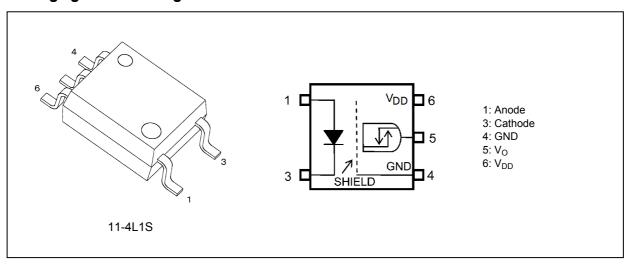
2. General

The Toshiba TLX9310 consists of a high-output an infrared LED coupled with a high-speed photo-diode-transistor chip. It is housed in the SO6 package. This photocoupler guarantees operation at up to 105 °C and on supplies from 2.7 V to 5.5 V. Since TLX9310 has guaranteed 0.3 mA low supply current (I_{DDL}/I_{DDH}), and 1.0 mA (T_{opr} = 105 °C) low threshold input current(I_{FHL}), it contributes to energy saving of devices. It can drive directly from a microcomputer for a low input current.

3. Features

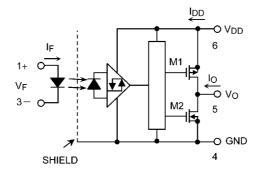
- (1) Buffer logic type (totem pole output)
- (2) Package: SO6
- (3) Operating temperature: -40 to 105 °C
- (4) Supply voltage: 2.7 to 5.5 V
- (5) Threshold input current: 1.0 mA (max)
- (6) Supply current: 0.3 mA (max)
- (7) Data transfer rate: 5 Mbps (typ.)
- (8) Common-mode transient immunity: ±25 kV/µs (min)
- (9) Isolation voltage: 3750 Vrms (min)
- (10) AEC-Q101 qualified

4. Packaging and Pin Assignment





5. Internal Circuit (Note)



Note: A 0.1- μF bypass capacitor must be connected between pin 6 and pin 4.

6. Principle of Operation

6.1. Truth Table

| Input | LED | Output |
|-------|-----|--------|
| Н | ON | Н |
| L | OFF | L |

6.2. Mechanical Parameters

| Characteristics | Min | Unit |
|------------------------------|-----|------|
| Creepage distances | 5.0 | mm |
| Clearance | 5.0 | |
| Internal isolation thickness | _ | |

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| | Characteristics | | Symbol | Note | Rating | Unit |
|----------|--------------------------------|---------------------------|-------------------------|----------|------------|-------|
| LED | Input forward current | | I _F | | 8 | mA |
| | Input forward current derating | $(T_a \ge 85 ^{\circ}C)$ | $\Delta I_F/\Delta T_a$ | | -0.05 | mA/°C |
| | Input forward current (pulsed) | | I _{FP} | (Note 1) | 1 | Α |
| | Input power dissipation | | P_D | | 20 | mW |
| | Input reverse voltage | | V _R | | 5 | V |
| Detector | Output current | | I _O | | 10 | mA |
| | Output voltage | | Vo | | 6 | V |
| | Supply voltage | | V_{DD} | | 6 | V |
| | Output power dissipation | | Po | | 20 | mW |
| Common | Operating temperature | | T _{opr} | | -40 to 105 | ℃ |
| | Storage temperature | | T _{stg} | | -55 to 125 | °C |
| | Lead soldering temperature | (10 s) | T _{sol} | | 260 | °C |
| | Isolation voltage | (AC, 60 s, R.H. ≤ 60 %) | BV _S | (Note 2) | 3750 | Vrms |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 1 μ s, 300 pps

Note 2: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

Rev.5.0



8. Recommended Operating Conditions (Note)

| Characteristics | Symbol | Note | Min | Тур. | Max | Unit |
|-----------------------|------------------|------|-----|------------|-----|------|
| Supply voltage | V_{DD} | | 2.7 | 3.0 to 5.0 | 5.5 | V |
| Operating temperature | T _{opr} | | -40 | | 105 | °C |

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor $(0.1\,\mu\text{F})$ should be connected between pin 6 (V_{DD}) and pin 4 (GND) to stabilize the operation of a high-gain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note: If the rising slope of the supply voltage (V_{DD}) for the detector is steep, stable operation of the internal circuits cannot be guaranteed.

Be sure to set 3.0 V/ μ s or less for a rising slope of the V_{DD}.

Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 105 °C, V_{DD} = 2.7 to 5.5 V)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------|------------------|-----------------|---|----------------------|------|-----|------|
| Input forward voltage | V _F | | I _F = 2 mA, T _a = 25 °C | 1.4 | 1.55 | 1.7 | V |
| | | | I _F = 2 mA | 1.2 | _ | 1.9 | |
| Input reverse current | I _R | | V _R = 5 V, T _a = 25 °C | _ | _ | 10 | μΑ |
| Input capacitance | Ct | | V = 0 V, f = 1 MHz , T _a = 25 °C | _ | 20 | | pF |
| Low-level output voltage | V _{OL} | Fig. 12.1 | $I_F = 0 \text{ mA}, I_O = 20 \mu\text{A}$ | _ | _ | 0.1 | V |
| | | | I _F = 0 mA, I _O = 3.2 mA | _ | _ | 0.4 | |
| High-level output voltage | V _{OH} | Fig. 12.2 | $I_F = 2 \text{ mA}, I_O = -20 \mu\text{A}$ | V _{DD} -0.1 | _ | _ | V |
| | | | I _F = 2 mA, I _O = -3.2 mA | V _{DD} -1.0 | _ | | |
| Low-level supply current | I _{DDL} | Fig. 12.3 | I _F = 0 mA | _ | _ | 0.3 | mA |
| High-level supply current | I _{DDH} | Fig. 12.4 | I _F = 2 mA | _ | _ | 0.3 | mA |
| Threshold input current (L/H) | I _{FLH} | | I_{O} = -3.2 mA, V_{O} > 2.4 V | _ | _ | 1.0 | mA |

Note: All typical values are at $V_{DD} = 5 \text{ V}$, $T_a = 25 ^{\circ}\text{C}$, unless otherwise noted.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Note | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------|----------------|----------|-------------------------------------|------------------|------|-----|------|
| Total capacitance (input to output) | Cs | (Note 1) | V _S = 0 V, f = 1 MHz | _ | 0.8 | _ | pF |
| Isolation resistance | R _S | (Note 1) | V _S = 500 V, R.H. ≤ 60 % | 10 ¹² | 1014 | _ | Ω |
| Isolation voltage | BVs | (Note 1) | AC, 60 s | 3750 | _ | _ | Vrms |

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



11. Switching Characteristics (Note) (Unless otherwise specified, T_a = -40 to 105 °C, V_{DD} = 2.7 to 5.5 V)

| Characteristics | Symbol | Note | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|---|------------------------------------|-----------------------|-----------------|---|-----|------|-----|-------|
| Propagation delay time (L/H) | t _{pLH} | (Note 1) | Fig.12.5 | V_{IN} = 3.3 V, R_{T} = 820 Ω | _ | _ | 250 | ns |
| Propagation delay time (H/L) | t _{pHL} | | | | _ | _ | 250 | |
| Pulse width distortion | t _{pHL} -t _{pLH} | | | | _ | _ | 50 | |
| Propagation delay skew (device to device) | t _{psk} | (Note 1), (Note 2) | | | _ | _ | 65 | |
| Propagation delay time (L/H) | t _{pLH} | (Note 1) | Fig.12.5 | $V_{IN} = 5 \text{ V}, R_T = 1.6 \text{ k}\Omega$ | _ | _ | 250 | ns |
| Propagation delay time (H/L) | t _{pHL} | | | | _ | _ | 250 | |
| Pulse width distortion | t _{pHL} -t _{pLH} | | | | _ | _ | 50 | |
| Propagation delay skew (device to device) | t _{psk} | (Note 1), (Note 2) | | | _ | _ | 65 | |
| Rise time | t _r | (Note 1) | Fig.12.5 | V_{IN} = 0 \rightarrow 3.3 V, R_T = 820 Ω , V_{DD} = 5 V | _ | 11 | _ | ns |
| Fall time | t _f | | | V_{IN} = 3.3 \rightarrow 0 V, R_T = 820 Ω , V_{DD} = 5 V | _ | 13 | _ | |
| High-level common-mode transient immunity | CM _H | | Fig.12.6 | V _{IN} = 3.3 V/5 V, V _{DD} = 2.7 V/5 V, | ±25 | ±40 | _ | kV/μs |
| Low-level common-mode transient immunity | CM _L | | | V _{CM} = 1000 V _{p-p} , T _a = 25 °C | | | | |

Note: All typical values are at V_{DD} = 5 V, T_a = 25 °C, unless otherwise noted.

Note: Recommendation input resistance conditions

 $\cdot V_{IN}$ = 3.3 V: R₁ = R₂ = 430 Ω

 \cdot V_{IN} = 5 V: R₁ = R₂ = 820 Ω

Note 1: f = 250 kHz, duty = 50 %, input current $t_r = t_f = 5 \text{ ns}$, C_L is less than 15 pF which includes probe and stray wiring capacitance.

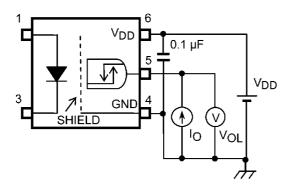
Note 2: The propagation delay skew, t_{psk} , is equal to the magnitude of the worst-case difference in t_{pHL} and/or t_{pLH} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc.).

Downloaded from Arrow.com.

Rev.5.0



12. Test Circuits



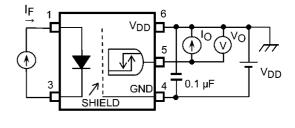


Fig. 12.1 V_{OL} Test Circuit

Fig. 12.2 V_{OH} Test Circuit

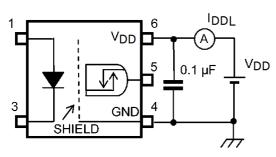


Fig. 12.3 I_{DDL} Test Circuit

 $V_{IN} = 3.3 \text{ V} / 5 \text{ V} (P.G.)$

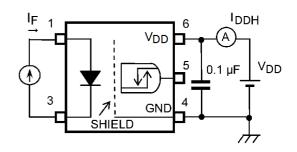
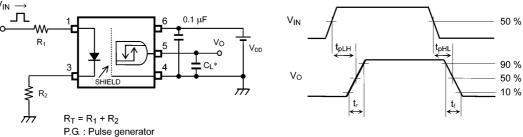


Fig. 12.4 I_{DDH} Test Circuit

 $(f = 250 \text{ kHz}, \text{duty} = 50 \%, \text{less than } t_r = t_f = 5 \text{ ns})$ VIN -___



*C_L is less than 15 pF which includes probe and stray wiring capacitance.

Fig. 12.5 Switching Time Test Circuit and Waveform

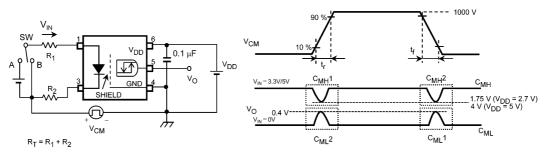


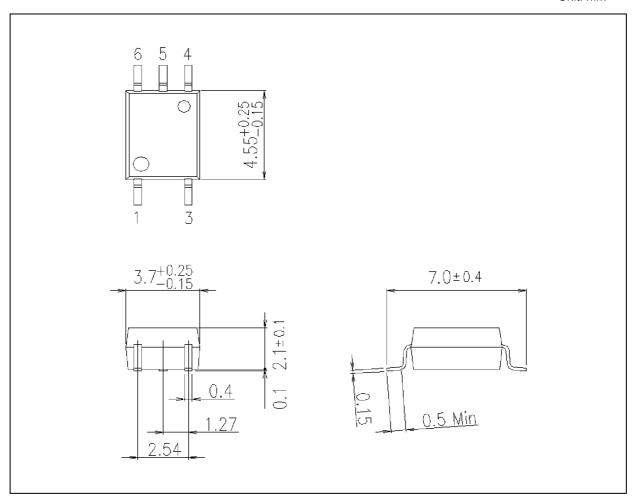
Fig. 12.6 Common-Mode Transient Immunity Test Circuit and Waveform

Downloaded from Arrow.com.



Package Dimensions

Unit: mm



Weight: 0.08 g (typ.)

| | Package Name(s) |
|------------------|-----------------|
| TOSHIBA: 11-4L1S | |

Rev.5.0



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- · TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's
 written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").
 - Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant.
 - IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.

For details, please contact your TOSHIBA sales representative or contact us via our website.

- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER,
 INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING
 WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND
 (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT,
 OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR
 PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor.
 Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/